





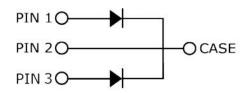
S3D30065D 650V SIC POWER SCHOTTKY RECTIFIER



Description

S3D30065D is a SiC Schottky rectifier packaged in TO-247AD(TO-247-3) case. The device is a high voltage Schottky rectifier that has very low total conduction losses and very stable switching characteristics over temperature extremes. The S3D30065D is ideal for energy sensitive, high frequency applications in challenging environments.

Circuit Diagram



Features

- 175°C T_J operation
- Ultra-low switching loss
- Switching speeds independent of operating temperature
- Low total conduction losses
- High forward surge current capability
- High package isolation voltage
- Terminals finish: 100% Pure Tin
- Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request

Applications

- Alternative energy inverters
- Power Factor Correction (PFC)
- Free-Wheeling diodes
- Switching supply output rectification
- Reverse polarity protection

Maximum Ratings(per leg)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{DC}	-	650	V
	I _{F (AV)1}	Tc=25°C	52	Α
Average Rectified Forward Current	I _{F (AV)2}	Tc=135°C	18	Α
	I _{F (AV)3}	Tc=155°C	15	
	I _{FRM1}	10ms, Half Sine pulse, T _J =25°C	50	Α
Repetitive Peak Forward Surge Current	I _{FRM2}	10ms, Half Sine pulse, T _J =110°C	35	Α
	I _{FSM1}	10ms, Half Sine pulse, T _J =25°C	102	Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM2}	10ms, Half Sine pulse, T _J =110°C	65	Α
Non Popolitive Book Forward Surge Current	I _{F,Max}	10µs. Pulse, T _J =25°C	865	Α
Non-Repetitive Peak Forward Surge Current	I _{F,Max}	10µs. Pulse, T _J =110°C	590	Α
Dawer Discination	P _{tot1}	T _J =25℃	179	W
Power Dissipation	P _{tot1}	T _J =110°C	78	W

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Electrical Characteristics(per leg)

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V_{F1}	@ 15A, Pulse, T _J = 25 °C	1.4	1.7	V
, , , , , , , , , , , , , , , , , , ,	V_{F2}	@ 15A, Pulse, T _J = 175 °C	1.6	2.0	V
Reverse Current*	I_{R1}		0.3	15	uA
	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 175 ^{\circ}\text{C}$	3	150	uA
Junction Capacitance	C_T	V _R =0V, T _J =25℃, f=1MHz	1243	-	pF
Reverse Recovery Charge	Qc	I _F = 15A, di/dt = 200A/μs VR = 400 V, T _J =25°C	77.5	-	nC
Capacitance Stored Energy	Ec	V _R = 400 V	18.99	-	μЈ

 $^{^*}$ Pulse width < 300 μ s, duty cycle < 2%

Thermal-Mechanical Specifications:

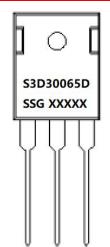
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +175	°C
Storage Temperature	T _{stg}	-	-55 to +175	°C
Typical Thermal Resistance Junction to Case	R _θ JC	DC operation	0.84(per leg) 0.42(both leg)	°C/W

Ordering Information

Device	Package	Shipping	
S3D30065D	TO-247AD(TO-247-3)	25pcs / tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

S3D = Device Type

= Package type = Porward Current (16A) = Reverse Voltage (650V) 30 065

SSG = SSG = Year ww = Week = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

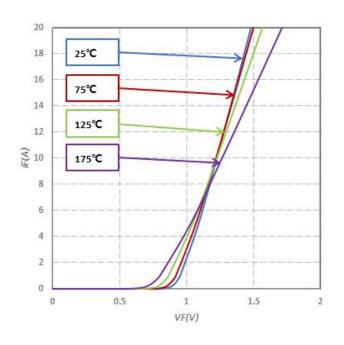
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Ratings and Characteristics Curves (per leg)



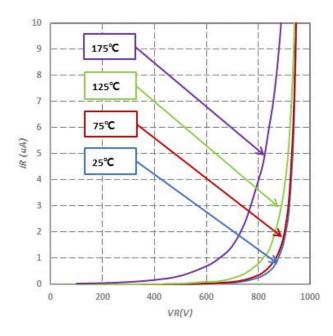


Fig.1-Typical Forward Voltage Characteristics

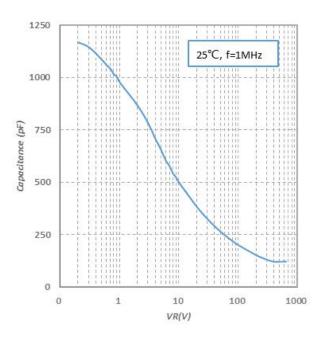


Fig.2-Typical Reverse Characteristics

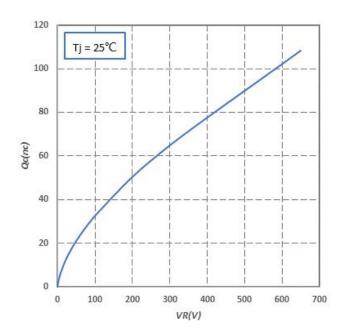


Fig.3-Capacitance vs. Reverse Voltage

Fig.4-Total Capacitance Charge vs. Reverse Voltage

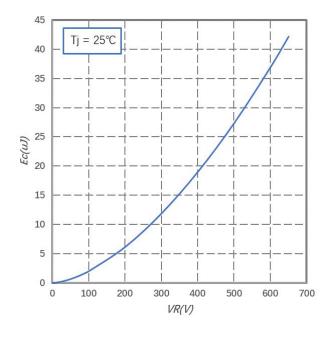
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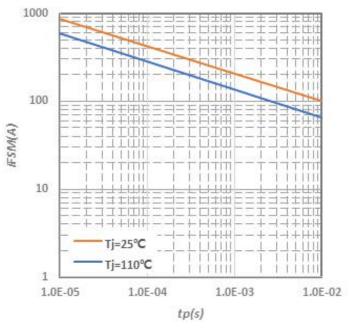


Fig.5-Capacitance Stored Energy

Fig.6-Non-repetitive peak forward surge current versus pulse duration (sinusoidal waveform)

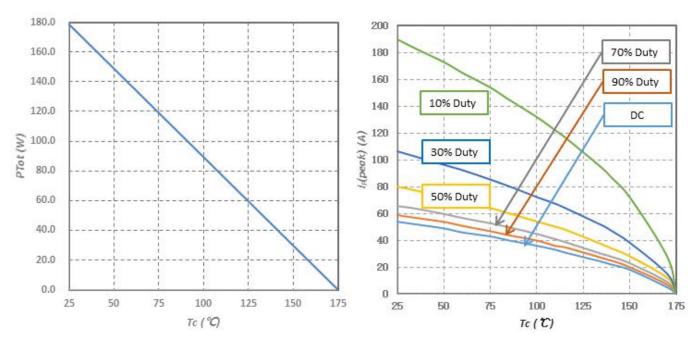


Fig.7-Power Derating

Fig.8-Current Derating

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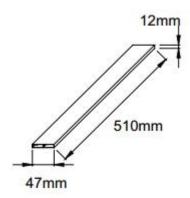
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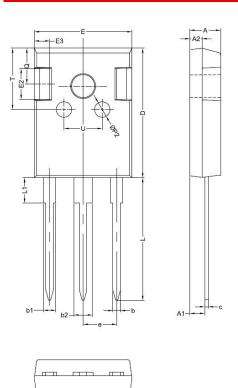


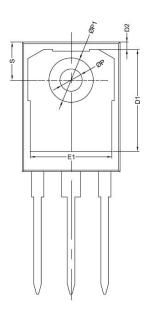


Tube Specification(TO-147-3)



Mechanical Dimensions TO-247AD





SYMBOL	Millimeters			
STWIBOL	MIN.	TYP.	MAX.	
Α	4.80		5.20	
A1	2.00		2.75	
A2	1.90		2.10	
b	1.00		1.40	
b1	1.80		2.40	
b2	2.80		3.40	
С	0.40		0.75	
D	19.80		21.20	
D1		16.55		
<u>D2</u> E		1.20		
	15.20		16.00	
E1		13.30		
E2		5.00		
E3		2.50		
е	5.20		5.70	
L	13.90		20.70	
L1	3.70		4.30	
Р	3.50		3.70	
P1	7.1		7.40	
P2		2.50		
Q S		5.80		
S	6.05		6.25	
Т		10.00		
U		6.20		

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